

### Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

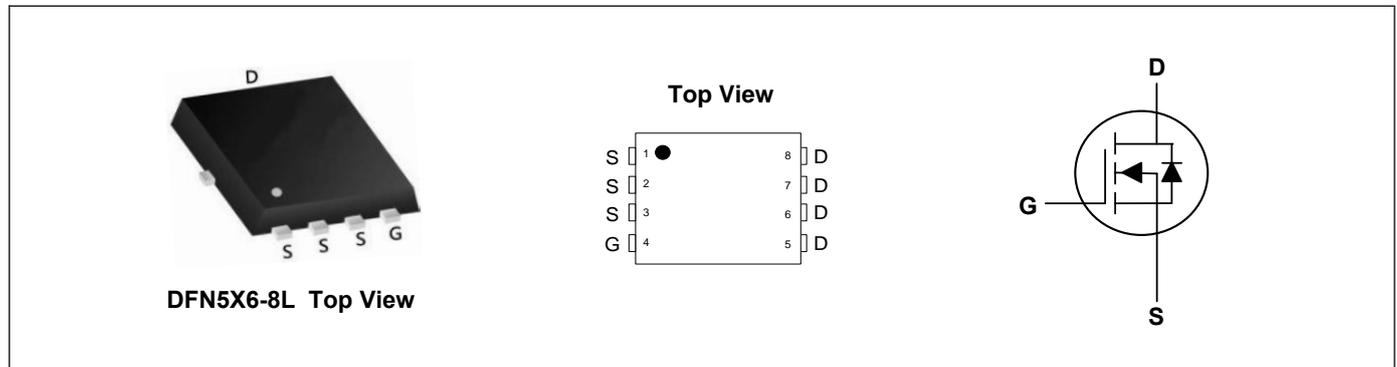
### Product Summary



$V_{DS}$	80	V
$I_D$	130	A
$R_{DS(ON)}$ Typ (at $V_{GS}=10V$ )	2.6	m $\Omega$

### Applications

- High Frequency Point-of-Load, Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch



### Absolute Maximum Ratings ( $T_C=25^\circ C$ , unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-Source Voltage	$V_{DS}$	80	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>1</sup>	$I_D@T_C=25^\circ C$	130	A
Pulsed Drain Current <sup>2</sup>	$I_{DM}$	520	A
Single Pulse Avalanche Energy <sup>3</sup>	$E_{AS}$	205	mJ
Total Power Dissipation <sup>4</sup>	$P_D$	132	W
Storage Temperature Range	$T_{STG}$	-55 to 150	$^\circ C$
Operating Junction Temperature Range	$T_J$	-55 to 150	$^\circ C$

### Thermal Characteristics

Parameter	Symbol	Typ	Max	Unit
Thermal Resistance Junction-Ambient <sup>1</sup>	$R_{\theta JA}$	---	62.5	$^\circ C/W$
Thermal Resistance Junction-Case <sup>1</sup>	$R_{\theta JC}$	---	0.95	$^\circ C/W$

**Electrical Characteristics ( $T_J=25^{\circ}\text{C}$ , unless otherwise noted)**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	80	---	---	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=50A$	---	2.6	3.3	$m\Omega$
Gate Threshold Voltage	$V_{GS(th)}$	$V_{GS}=V_{DS}, I_D=250\mu A$	2.0	---	4.0	V
Drain-Source Leakage Current	$I_{DSS}$	$V_{DS}=80V, V_{GS}=0V, T_J=25^{\circ}\text{C}$	---	---	1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	---	---	$\pm 100$	nA
Total Gate Charge	$Q_g$	$V_{DS}=40V, V_{GS}=10V, I_D=20A$	---	70	---	nC
Gate-Source Charge	$Q_{gs}$		---	21	---	
Gate-Drain Charge	$Q_{gd}$		---	11	---	
Turn-On Delay Time	$T_{d(on)}$	$V_{DS}=40V, V_{GS}=10V, R_G=2\Omega, I_D=20A$	---	19	---	ns
Rise Time	$T_r$		---	7	---	
Turn-Off Delay Time	$T_{d(off)}$		---	37	---	
Fall Time	$T_f$		---	38	---	
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V, f=1\text{MHz}$	---	5720	---	pF
Output Capacitance	$C_{oss}$		---	2080	---	
Reverse Transfer Capacitance	$C_{rss}$		---	107	---	

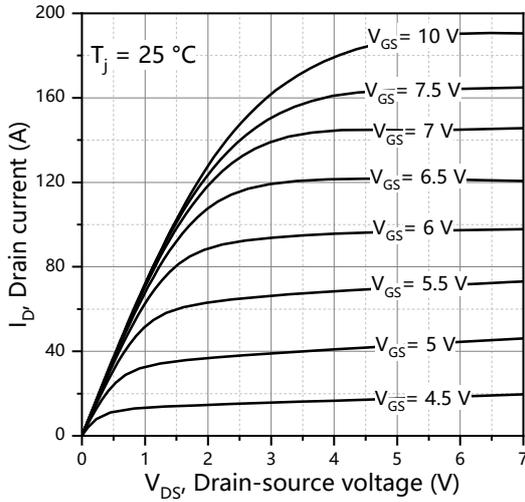
**Drain-Source Diode Characteristics**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Diode Forward Voltage <sup>2</sup>	$V_{SD}$	$V_{GS}=0V, I_S=12A, T_J=25^{\circ}\text{C}$	---	---	0.95	V
Reverse recovery time	$t_{rr}$	$I_F=20A, diF/dt=100A/\mu s$	---	65	---	ns
Reverse recovery charge	$Q_{rr}$		---	138	---	nC

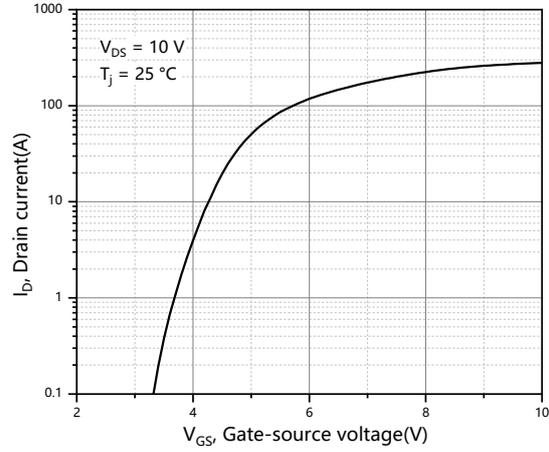
**Note:**

1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
2. The data tested by pulsed, pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$
3. The EAS data shows Max. rating. The test condition is  $V_{DD}=20V, V_{GS}=10V, L=0.5mH, I_{AS}=32A$
4. The power dissipation is limited by 150 $^{\circ}\text{C}$  junction temperature

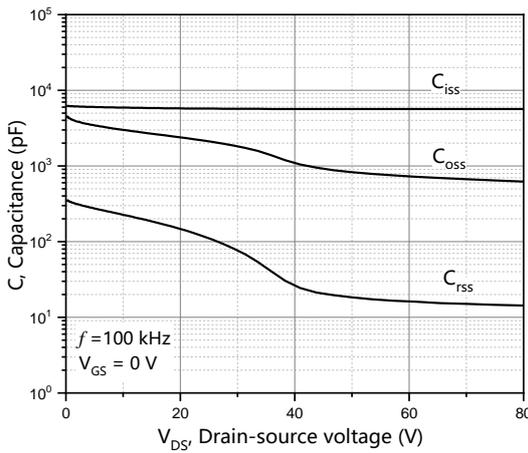
**Typical Characteristics**



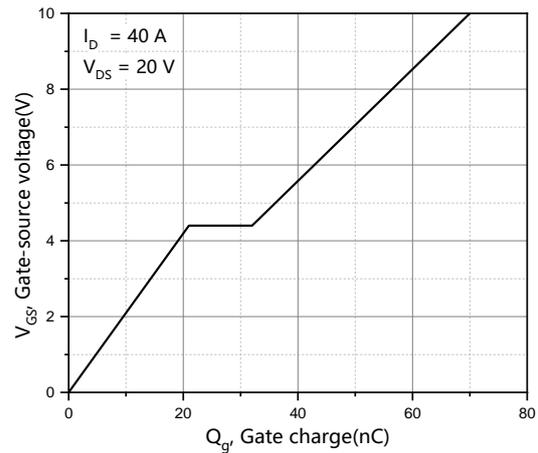
**Figure 1. Typ. output characteristics**



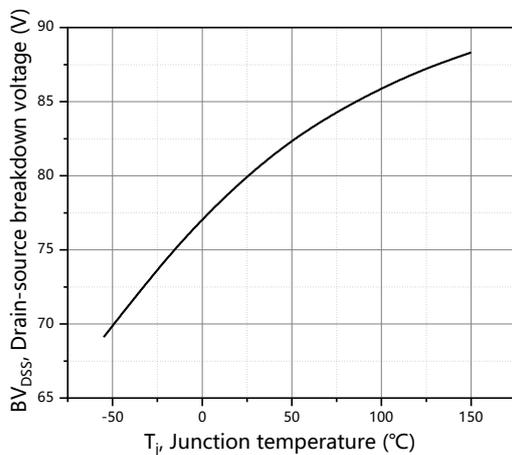
**Figure 2. Typ. transfer characteristics**



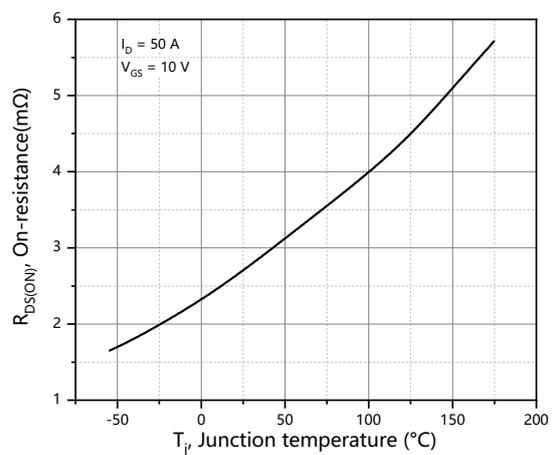
**Figure 3. Typ. capacitances**



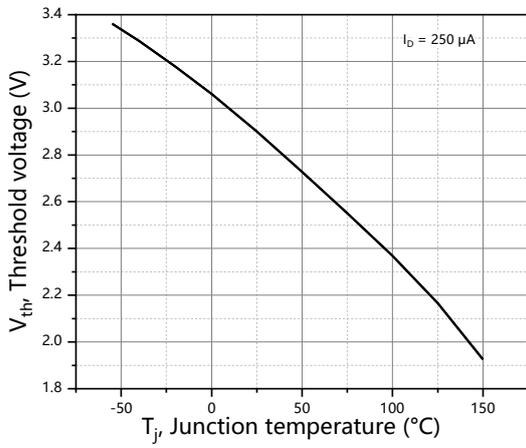
**Figure 4. Typ. gate charge**



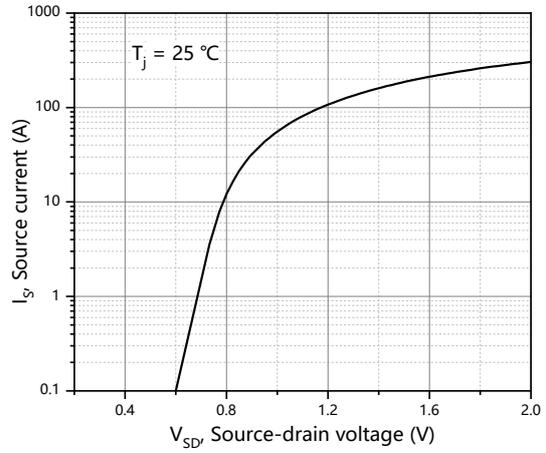
**Figure 5. Drain-source breakdown voltage**



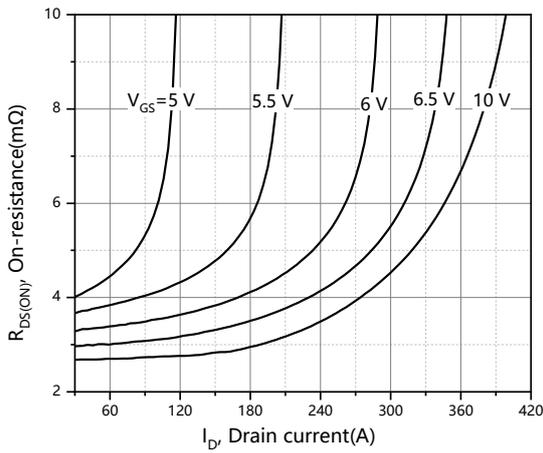
**Figure 6. Drain-source on-state resistance**



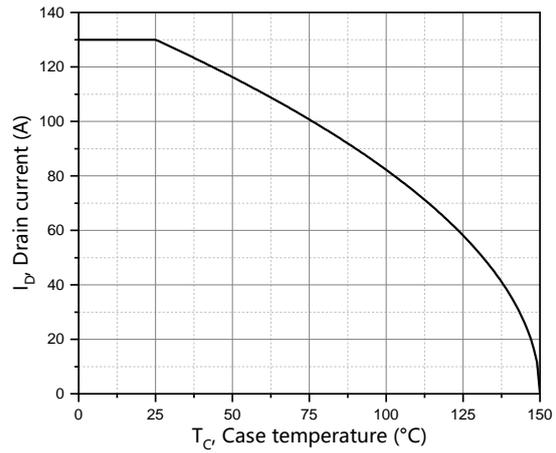
**Figure 7. Threshold voltage**



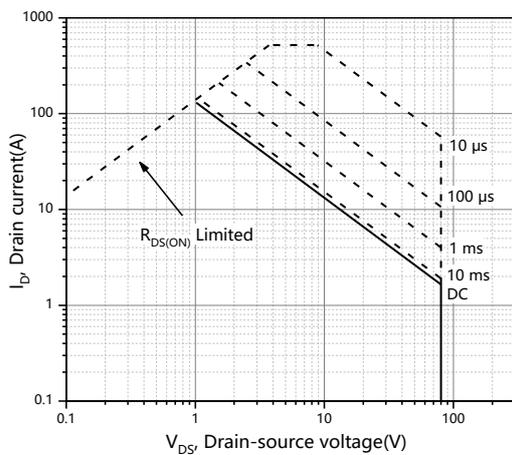
**Figure 8. Forward characteristic of body diode**



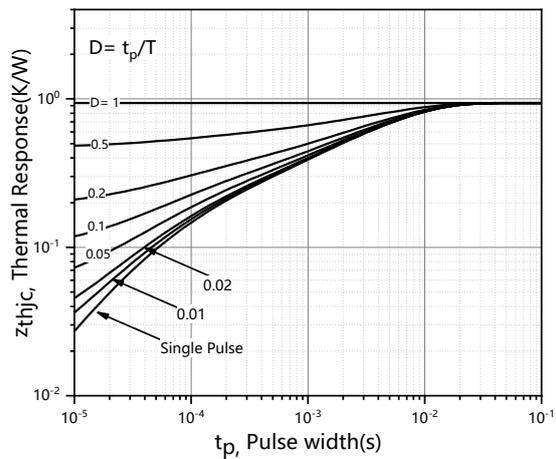
**Figure 9. Drain-source on-state resistance**



**Figure 10. Drain current**

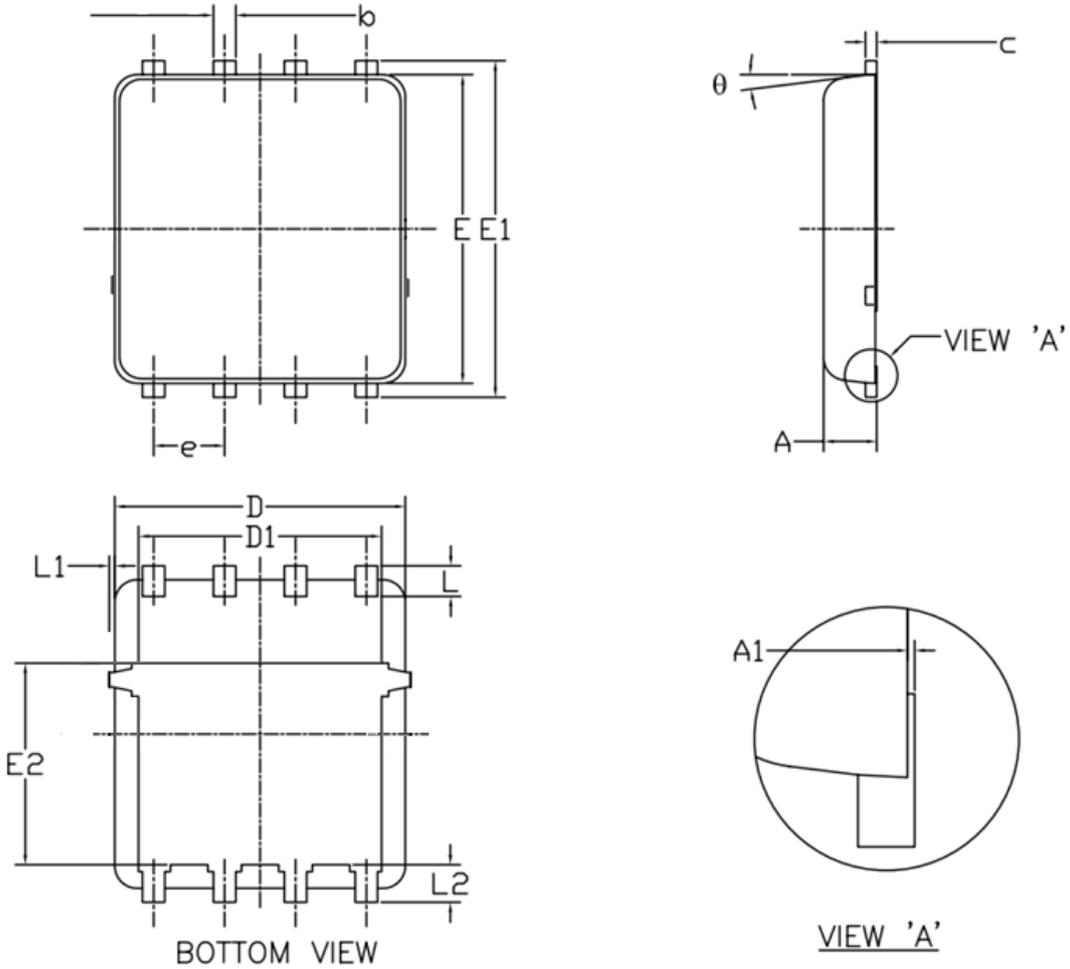


**Figure 11. Safe operation area**



**Figure 12. Max. transient thermal impedance**

**DFN5X6-8L Package Outline Dimensions**



Symbol	Dimensions (unit:mm)			Symbol	Dimensions (unit:mm)		
	Min	Typ	Max		Min	Typ	Max
<b>A</b>	0.90	1.00	1.20	<b>E1</b>	5.90	6.10	6.35
<b>A1</b>	0.00	--	0.05	<b>E2</b>	3.38	3.58	3.92
<b>b</b>	0.30	0.40	0.51	<b>e</b>	1.27 BSC		
<b>c</b>	0.20	0.25	0.33	<b>L</b>	0.51	0.61	0.71
<b>D</b>	4.80	4.90	5.40	<b>L1</b>	--	--	0.15
<b>D1</b>	3.61	4.00	4.25	<b>L2</b>	0.41	0.51	0.61
<b>E</b>	5.65	5.80	6.06	<b><math>\theta</math></b>	0°	--	12°

## Printing Information

ATC           =====Brand

XXXXXXX       =====Material Code

XXYY           =====XX Representative Year  
                  YY Representative Weeks